

## 1200V SiC Schottky Diode

#### **FEATURES**

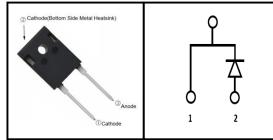
- Low Conduction and Swiitch Loss
- Positive Temperature Coefficient on VF
- Temperature Independent Switching Behavior
- Fast Reverse Recovery
- High Surge Current Capability
- Pb-free lead plating

#### **BENEFITS**

- Higher System Efficiency
- Parallel Device Convenience
- High Temperature Application
- High Frequency Operation
- Hard Switching & High Reliability
- Environmental Protection

#### **APPLICATIONS**

- Switch Mode Power Supply (SMPS)
- Uninterruptible Power Supply (UPS)
- Power Factor Correction (PFC)
- Solar/ Wind Renewable Energy
- Power Inverters
- Motor Drives





Device Marking and Package Information				
Device	Package	Marking		
C2S120F015B	TO-247-2L	C2S120F015B		

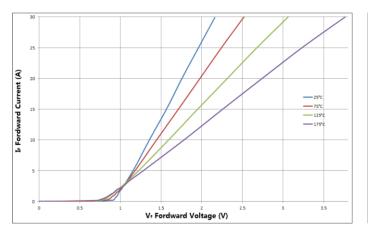
Absolute Maximum Ratings T <sub>C</sub> = 25°C, unless otherwise noted					
Parameter	Symbol	Test Conditions	Value	Unit	
Peak Repetitive Reverse Voltage	$V_{RRM}$	T <sub>J</sub> = 25°C	1200	V	
Peak Reverse Surge Voltage	V <sub>RSM</sub>	T <sub>J</sub> = 25°C	1200	V	
DC Blocking Voltage	V <sub>R</sub>	T <sub>J</sub> = 25°C	1200	V	
Continuous Forward Current	I <sub>F</sub>	T <sub>J</sub> ≤ 135°C	15	Α	
Repetitive Peak Forward Surge Current	I <sub>FRM</sub>	$T_C = 25^{\circ}C$ , $T_P = 8.3$ ms Half Sine Wave	135	А	
Maximum Case Temperature	T <sub>C</sub>		135	°C	
Operating Junction and Storage Temperature	T <sub>J</sub> , T <sub>stg</sub>		-55~175	°C	

Thermal Resistance					
Parameter	Symbol	Value	Unit		
Thermal Resistance, Junction-to-Case	R <sub>thJC</sub>	0.85	°C/W		



<b>Specifications</b> T <sub>J</sub> = 25°C, unless otherwise noted						
Devenuetes	C. mahal	Test Conditions	Value		l lea is	
Parameter	Symbol	rest Conditions	Тур.	Max.	Unit	
Forward Voltage	V <sub>F</sub>	I <sub>F</sub> = 15A, T <sub>J</sub> = 25°C	1.57	1.8	V	
		I <sub>F</sub> = 15A, T <sub>J</sub> = 175°C	2.25	2.5	V	
Reverse Current	I <sub>R</sub>	V <sub>R</sub> =1200V, T <sub>J</sub> = 25°C	5	20	μA	
		V <sub>R</sub> =1200V, T <sub>J</sub> = 175°C	20	200	μΑ	
Total Capacitive Charge	Q <sub>C</sub>	$I_F = 15A$ , di/dt =200A / $\mu$ s $V_R = 1200V$ , $T_J = 25$ °C	48		nC	
Total Capacitance	С	V <sub>R</sub> =0V, T <sub>J</sub> = 25°C, , f =1 MHz 940				
		V <sub>R</sub> =400V, T <sub>J</sub> = 25°C, , f =1 MHz	70		pF	
		V <sub>R</sub> =800V, T <sub>J</sub> = 25°C, , f =1 MHz	57			





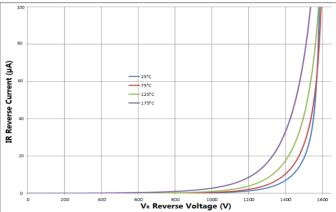
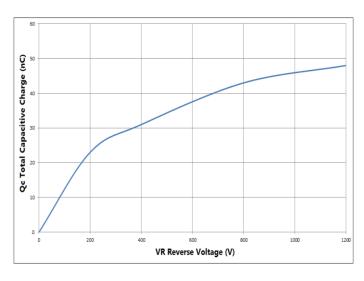


Fig. 1 Forward Characteristics

Fig. 2 Reverse Characteristics



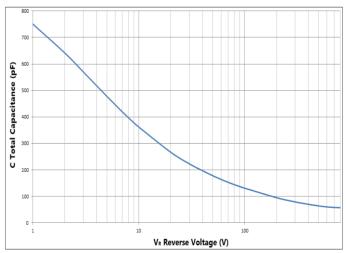


Fig. 3 Total Capacitance Charge vs. Reverse Voltage

Fig. 4 Total Capacitance vs. Reverse Voltage

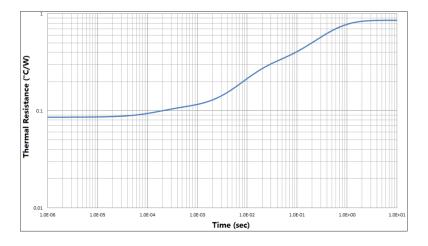
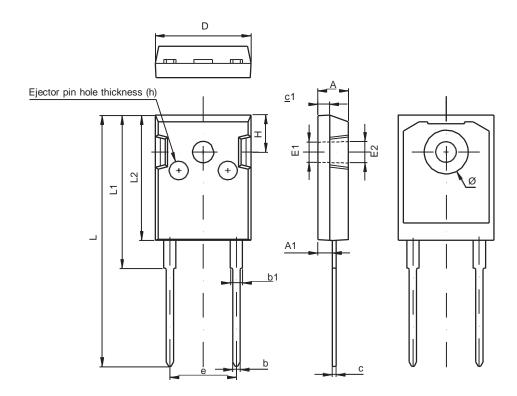


Fig. 5 Transient Thermal Impedance



# TO-247-2



### **TO-247-2L DIMENSIONS**

SYMBOL	DIMENSIONS II	N MILLIMETERS	DIMENSIONS IN INCHES		
	MIN.	MAX.	MIN.	MAX.	
A	4.850	5.150	0.191	0.200	
A1	2.200	2.600	0.087	0.102	
b	1.000	1.400	0.039	0.055	
b1	1.800	2.200	0.071	0.087	
С	0.500	0.700	0.020	0.028	
c1	1.900	2.100	0.075	0.083	
D	15.450	15.750	0.608	0.620	
E1	3.500 Ref.		0.138 Ref.		
E2	3.600 Ref.		0.142 Ref.		
L	40.900	41.300	1.610	1.626	
L1	24.800	25.100	0.976	0.988	
L2	20.300	20.600	0.799	0.811	
Ø	7.100	7.300	0.280	0.287	
е	10.900 Typ.		0.429 Typ.		
Н	5.980 Typ.		0.235 Typ.		
h	0.000	0.300	0.000	0.012	



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